



SIC SCHOTTKY DIODE MODULE

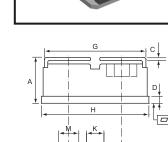
Features

- High surge current capable
- Zero reverse recovery current
- High bandwidth
- · Isolation type package
- V_{DC} 1700 V
- I_F(T_C<135°C) 2×100 A
- Temperature independent switching behavior

SOT-227

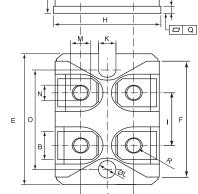
Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices without thermal runaway



Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- Induction heating

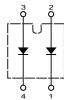


Maximum Ratings

Operating Junction Temperature : -55°C to +175°C

Storage Temperature : -55 $^{\circ}$ C to +175 $^{\circ}$ C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×100-170P2B	1700V	1700V



parallel

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F T _C =135 °C		100		
Surge non-repetitive forward current	I _{FSM}	T_{C} =25 °C, t_{p} =8.3 ms	800		
sine halfwave (per diode)	1 GIVI	$T_{\rm C}$ =150 °C, $t_{\rm p}$ =8.3 ms	500	Α	
Non-repetitive peak forward current	I _{F,max}	T_{C} =25 °C, t_{p} =10 μ s	3200	3200	
(per diode)		T_{C} =150 °C, t_{p} =10 μ s	2000		
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1700	٧	
Isolation voltage between all terminals and baseplate	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA		V	
Mounting torque		To heatsink	1.3	Nm	
Mounting torque		To terminal	1.1	INIII	

DIMENSIONS						
	INCH	HES	ММ			
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
E	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
- 1	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
М	0.181	0.197	4.60	5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					



CSRI2×100-170P2B

Electrical Characteristics, at T_j =25 °C, unless otherwise specified. (per diode)

Static Characteristics	Cumbal	Symbol Conditions	Values			
	Symbol		min.	typ.	max.	Unit
DC blocking voltage	V_{DC}		1,700	-	-	
Diode forward voltage	V _F	I _F =100A, T _j =25 °C	-	1.6	1.8	V
		I _F =100A, T _j =175 °C	-	2.4	2.9	
	l-	V _R =1,700V, T _j =25 °C	-	60	100	
Reverse current	I _R	V _R =1,700V, T _j = 175 °C	-	100	500	μΑ

AC Characteristics (per diode)

Static Characteristics	Symbol Condition	O and distance	Values			
		Conditions	min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R = 800V, I _F = 100A dI/dt = 333A/µs, T _j = 25 °C	-	90	-	nC
Total capacitance	O	V _R =1V, f=1 MHz T _j =25 °C	-	10,860	-	pF
		V _R =800V, f=1 MHz T _j =25 °C	-	375	-	
		V _R =1000V, f=1 MHz T _j =25 °C	-	340	-	

Thermal Characteristics (per diode)

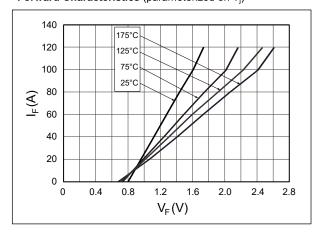
Static Characteristics	Symphol	Values	Unit	
Static Characteristics	Symbol	typ.		
Thermal resistance from junction to case	$R_{ heta JC}$	0.14	°C/W	



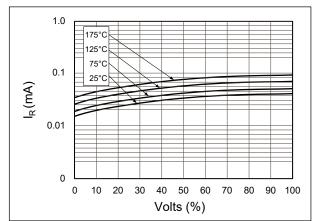


Typical Performance

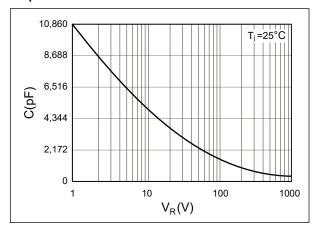
Forward Characteristics (parameterized on T_j)



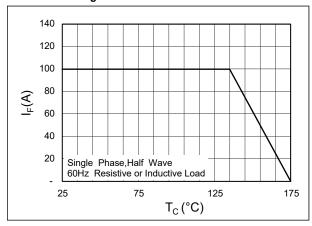
Reverse Characteristics (parameterized on Tj)



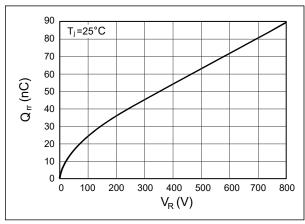
Capacitance



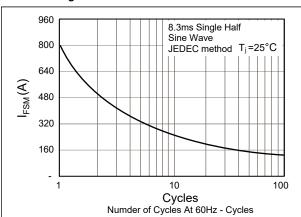
Current Derating



Recovery Charge



Forward Surge Current





Disclaimer

DACO Semiconductor reserves the right to make modifications, enhancements, improvements, corrections, or other changes to this document and any product described herein without prior notice. For the most up-to-date version, please visit our website.

DACO Semiconductor makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does DACO Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any liability, including without limitation special, consequential or incidental damages.

Purchasers are responsible for its products and applications using DACO Semiconductor products, including compliance with all laws, regulations, and safety requirements or standards, regardless of any support or application information provided by DACO Semiconductor. "Typical" parameters that may be provided in DACO Semiconductor datasheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by the customer's technical experts.

DACO Semiconductor products are not designed, authorized, or warranted to be suitable for use in life support, life-critical or safety-critical systems, or equipment, nor in applications where failure or malfunction of DACO Semiconductor's product can reasonably be expected to result in personal injury, death or severe property or environmental damage. DACO Semiconductor accepts no liability for the inclusion and/or use of DACO Semiconductor's products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Purchasers who buy or use DACO Semiconductor products for any unintended or unauthorized applications are required to indemnify and absolve DACO Semiconductor, its suppliers, and distributors from any claims, costs, damages, expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that DACO Semiconductor was negligent regarding the design or manufacture of the part.

No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or by any information storage and retrieval system, or otherwise, without the prior written permission of DACO Semiconductor Co., Ltd.